National Taiwan University
Department of Electrical Engineering

Microelectronics – I
Fall 2006

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Office hour: TBD

Class Time:  TUE 9:10 – 12:00

Class Room: 電二254

Textbooks:

Grading: Grades will be based on a 100 point scale.
Midterm    50%  (November 14, 2006)
Final      50%  (January 9, 2007)

Homework: Homework won’t be collected and graded. However, the solutions will be posted on the course website. The students are expected to do the homework and discuss with the TA if there is any question. Homework questions will appear in the exam up to 20%.

Class Website: http://cc.ee.ntu.edu.tw/~emery/Courses.htm

What is Expected of Students:
[1] All students are required to follow the academic honor codes established by National Taiwan University.
[2] All students are expected to be respectful of other students.
[3] All students are responsible for the materials covered and/or assigned in class regardless of whether they attend class.
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<th>Topic</th>
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<td>Operational Amplifier&lt;br&gt;Applications of Op Amp&lt;br&gt;Characteristics of Op Amp</td>
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<td>Chapter 5</td>
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